

## P-Channel Enhancement Mode Field Effect Transistor

### General Description

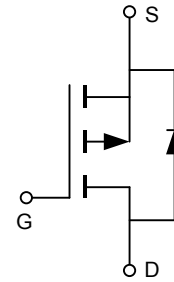
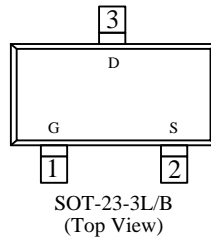
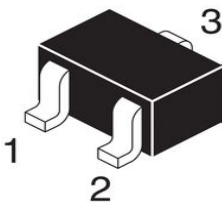
Product Summary		
$V_{DS}$	$I_D$	$R_{DS(ON)}(m\Omega)TYP$
-30V	-4.4A	52 @ $V_{GS}=-10V$
		65 @ $V_{GS}=-4.5V$

### Features

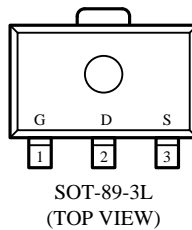
- Super high dense cell design for low  $R_{DS(ON)}$
- Rugged and reliable
- Simple drive requirement
- SOT-23-3L/B package

### Package

- SOT-23-3L/B



- SOT-89-3L



### Ordering Information

Part Number	Storage Temperature	Package	Devices Per Reel
PN2311	-55°C to +150°C	SOT-23-3L/B	3000
	-55°C to +150°C	SOT-89-3L	3000